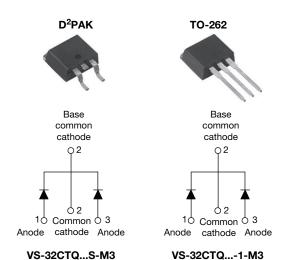


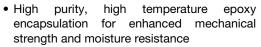
High Performance Schottky Rectifier, 2 x 15 A



PRODUCT SUMMARY	PRODUCT SUMMARY						
I _{F(AV)}	2 x 15 A						
V_{R}	25 V, 30 V						
V _F at I _F	0.40 V						
I _{RM} max.	97 mA at 125°C						
T _J max.	150 °C						
E _{AS}	13 mJ						
Package	TO-263AB (D ² PAK), TO-262AA						
Diode variation	Common cathode						

FEATURES

- 150 °C T_J operation
- · Low forward voltage drop
- · High frequency operation





- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified meets JESD 201 class 1A whisker
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-32CTQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	30	A				
V _{RRM}		25/30	V				
I _{FSM}	t _p = 5 μs sine	900	A				
V _F	15 A _{pk} , T _J = 125 °C	0.40	V				
T _J	Range	-55 to +150	°C				

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-32CTQ025SHM3 VS-32CTQ025-1HM3		UNITS
Maximum DC reverse voltage	V_{R}	25	30	V
Maximum working peak reverse voltage	V_{RWM}	25	30	V



VS-32CTQ...SHM3, VS-32CTQ...-1HM3 Series

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ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 115 °C	50 % duty cycle at T _C = 115 °C, rectangular waveform				
Maximum peak one cycle non-repetitive surge current		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	900	Α		
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse V _{RRM} applied		250			
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.20 \text{A}, L = 11.10 \text{mH}$		13	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim	•	3	А		

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		15 A	T _{.1} = 25 °C	0.49		
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	30 A	1J=25 C	0.58	V	
	VFM (*)	15 A	T _{.1} = 125 °C	0.40		
		30 A	1	0.53		
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	1.75	mA	
See fig. 2	IRM ('')	T _J = 125 °C	v _R = nateu v _R	97		
Threshold voltage	V _{F(TO)}	T T mayimum		0.233	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		9.09	mΩ	
Maximum junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		1300	pF	
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body			nH	
Maximum voltage rate of change	dV/dt	Rated V _R	Rated V _R 10 000			

Note

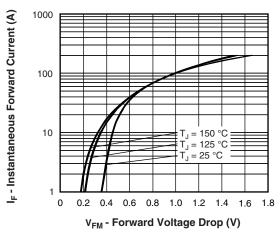
 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C		
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation See fig. 4	3.25	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	C/VV		
Approximate weight				2	g		
Approximate weight				0.07	oz.		
Mounting torque	minimum			6 (5)	kgf · cm		
Wounting torque	maximum			12 (10)	(lbf \cdot in)		
			Case style D ² PAK	32CTQ025SH			
Marking device			Case Style D-FAK	32CTQ030SH			
			Case style TO-262	32CTQ	025-1H		
			Case style 10-202	32CTQ	030-1H		

1000

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T_J = 150 °C

T_J = 125 °C

T_J = 100 °C

T_J = 75 °C

T_J = 25 °C

T_J = 25 °C

T_J = 25 °C

T_J = 8everse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

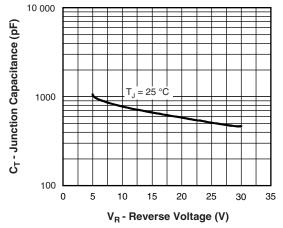


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

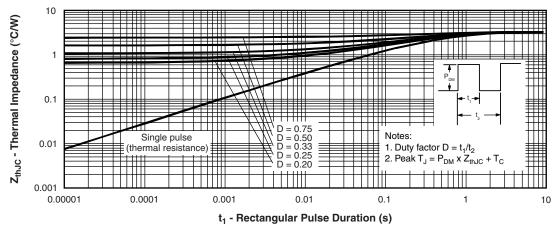


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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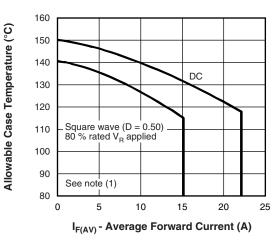


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

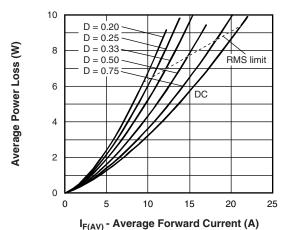


Fig. 6 - Forward Power Loss Characteristics

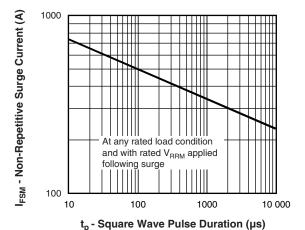


Fig. 7 - Maximum Non-Repetitive Surge Current

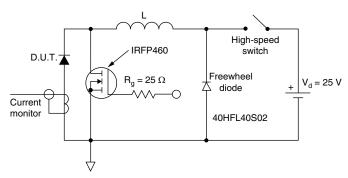


Fig. 8 - Unclamped Inductive Test Circuit

Note

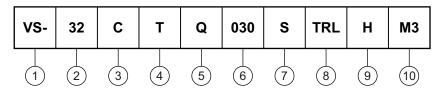
(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

VS-32CTQ...SHM3, VS-32CTQ...-1HM3 Series

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (30 A)

3 - Circuit configuration: C = common cathode

4 - T = TO-220

- Schottky "Q" series

6 - Voltage ratings — 025 = 25 V 030 = 30 V

7 - • S = D²PAK

• -1 = TO-262

8 - • None = tube

• TRL = tape and reel (left oriented - for D²PAK only)

• TRR = tape and reel (right oriented - for D²PAK only)

9 - H = AEC-Q101 qualified

- M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-32CTQ025SHM3	50	1000	Antistatic plastic tubes				
VS-32CTQ025STRRHM3	800	800	13" diameter reel				
VS-32CTQ025STRLHM3	800	800	13" diameter reel				
VS-32CTQ025-1HM3	50	1000	Antistatic plastic tubes				
VS-32CTQ030SHM3	50	1000	Antistatic plastic tubes				
VS-32CTQ030STRRHM3	800	800	13" diameter reel				
VS-32CTQ030STRLHM3	800	800	13" diameter reel				
VS-32CTQ030-1HM3	50	1000	Antistatic plastic tubes				

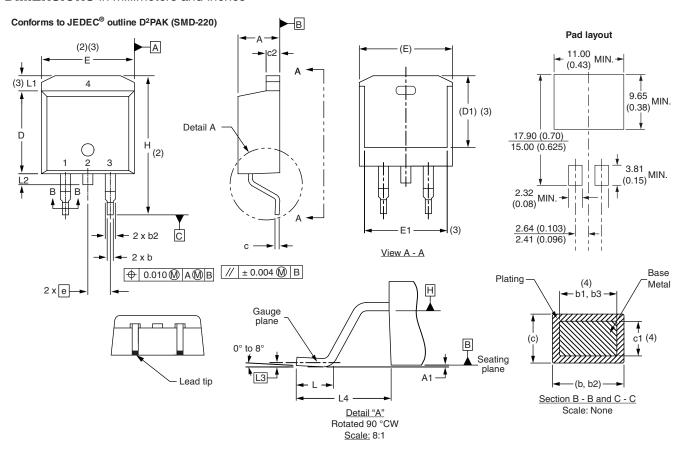
LINKS TO RELATED DOCUMENTS									
Dimensions	Dimensions TO-263AB (D ² PAK) <u>www.vishay.com/doc?95046</u>								
Dimensions	TO-262AA	www.vishay.com/doc?95419							
Part marking information	TO-263AB (D ² PAK)	www.vishay.com/doc?95444							
Part marking information	TO-262AA	www.vishay.com/doc?95443							
Packaging information		www.vishay.com/doc?95032							



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	MILLIMETERS		HES	NOTES		SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOIES	STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

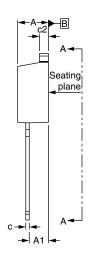


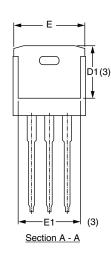
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TO-262

DIMENSIONS in millimeters and inches

Modified JEDEC outline TO-262 (Datum A)—(2) (3) (3) L1 D D D A (2) (3) L2 B B B B C C C C C C C A A (2)



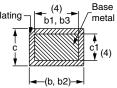


♦0.010**M**|**AM**|**B**|

Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode
3. - Anode



Section B - B and C - C Scale: None

CVMDOL	MILLIM	ETERS	INC	HES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06		0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
Е	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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